## VS-42CTQ030SHM3, VS-42CTQ030-1HM3

Vishay Semiconductors

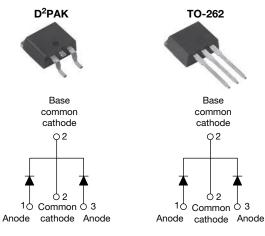
RoHS

COMPLIANT

**HALOGEN** 

FREE

## High Performance Schottky Rectifier, 2 x 20 A



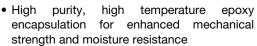
| VS-42C1 | CO30SHM3 |  |
|---------|----------|--|
|         |          |  |

VS-42CTQ030-1HM3

| PRODUCT SUMMARY                  |   |  |  |  |
|----------------------------------|---|--|--|--|
| I <sub>F(AV)</sub>               | 2 x 20 A                                |  |  |  |
| $V_{R}$                          | 30 V                                    |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.38 V                                  |  |  |  |
| I <sub>RM</sub>                  | 183 mA at 125 °C                        |  |  |  |
| T <sub>J</sub> max.              | 150 °C                                  |  |  |  |
| E <sub>AS</sub>                  | 13 mJ                                   |  |  |  |
| Package                          | TO-263AB (D <sup>2</sup> PAK), TO-262AA |  |  |  |
| Diode variation                  | Common cathode                          |  |  |  |

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- · Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability





- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### **DESCRIPTION**

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |  |                           |    |  |  |  |
|-----------------------------------|--|---------------------------|----|--|--|--|
| SYMBOL                            | CHARACTERISTICS  | CHARACTERISTICS VALUES UN |    |  |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                                   | 40                        | A  |  |  |  |
| V <sub>RRM</sub>                  |  | 30                        | V  |  |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 µs sine                             | 1100                      | Α  |  |  |  |
| V <sub>F</sub>                    | 20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg) | 0.38                      | V  |  |  |  |
| T <sub>J</sub>                    | Range  | -55 to 150                | °C |  |  |  |

| VOLTAGE RATINGS                      |           |                                     |       |  |  |
|--------------------------------------|-----------|-------------------------------------|-------|--|--|
| PARAMETER                            | SYMBOL    | VS-42CTQ030SHM3<br>VS-42CTQ030-1HM3 | UNITS |  |  |
| Maximum DC reverse voltage           | $V_{R}$   | 30                                  | V     |  |  |
| Maximum working peak reverse voltage | $V_{RWM}$ | 30                                  | V     |  |  |



# VS-42CTQ030SHM3, VS-42CTQ030-1HM3

# Vishay Semiconductors

| ABSOLUTE MAXIMUM RATINGS                |                         |                    |   |   |       |    |  |  |
|---|-------------------------|--------------------|---|---|-------|----|--|--|
| PARAMETER                               |                         | SYMBOL             | TEST COND   | VALUES  | UNITS |    |  |  |
| Maximum average forward current         | per leg                 | I=                 | 50 % duty cycle at T <sub>C</sub> = 121 °C, rectangular waveform  |   | 20    |    |  |  |
| See fig. 5                              | per device              | I <sub>F(AV)</sub> | 30 % duty cycle at 1°C = 121 V  | Cycle at 10 = 121 C, rectangular wavelorm         |       | А  |  |  |
| Maximum peak one cycle non-repetitive   |                         |                    | 5 μs sine or 3 μs rect. pulse   | Following any rated load condition and with rated | 1100  |    |  |  |
| surge current per leg<br>See fig. 7     | per leg I <sub>FS</sub> |                    | 10 ms sine or 6 ms rect. pulse  | V <sub>RRM</sub> applied                          | 360   |    |  |  |
| Non-repetitive avalanche energy per leg |                         | E <sub>AS</sub>    | $T_{J} = 25  ^{\circ}\text{C},  I_{AS} = 3  \text{A},  L = 2.90  \text{mH}$   |   | 13    | mJ |  |  |
| Repetitive avalanche current per leg    |                         | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical |   | 3     | А  |  |  |

| ELECTRICAL SPECIFICATIONS                          |                                |  |                                       |        |      |  |  |
|--|--------------------------------|--|---------------------------------------|--------|------|--|--|
| PARAMETER  | SYMBOL                         | TEST CO  | TEST CONDITIONS                       |        |      |  |  |
|  |                                | 20 A   | - T <sub>.1</sub> = 25 °C             | 0.48   |      |  |  |
| Maximum forward voltage drop per leg<br>See fig. 1 | V <sub>FM</sub> <sup>(1)</sup> | 40 A   | - IJ=25 C                             | 0.57   | V    |  |  |
|  | V FM (1)                       | 20 A   | - T <sub>.1</sub> = 125 °C            | 0.38   |      |  |  |
|  |                                | 40 A   | - IJ = 125 C                          | 0.51   |      |  |  |
| Maximum reverse leakage current per leg            | I <sub>RM</sub> <sup>(1)</sup> | T <sub>J</sub> = 25 °C                               | V Datad V                             | 3      | mA   |  |  |
| See fig. 2   | IRM ('')                       | T <sub>J</sub> = 125 °C                              | V <sub>R</sub> = Rated V <sub>R</sub> | 183    |      |  |  |
| Threshold Voltage                                  | V <sub>F(TO)</sub>             | T <sub>.I</sub> =T <sub>.I</sub> maximum             |                                       | 0.22   | V    |  |  |
| Forward slope resistance                           | r <sub>t</sub>                 | I J = I J III axii II u III                          |                                       | 6.76   | mΩ   |  |  |
| Maximum junction capacitance per leg               | C <sub>T</sub>                 | V <sub>R</sub> = 5 V <sub>DC</sub> (test signal rang | 2840                                  | pF     |      |  |  |
| Typical series inductance per leg                  | L <sub>S</sub>                 | Measured lead to lead 5 mm from package body         |                                       |        | nΗ   |  |  |
| Maximum voltage rate of change                     | dV/dt                          | Rated V <sub>R</sub>                                 |                                       | 10 000 | V/µs |  |  |

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300 µs, duty cycle < 2 %

| THERMAL - MECHAI  | NICAL SPI | ECIFICAT                          | ions                                 |            |                  |
|---|-----------|-----------------------------------|--------------------------------------|------------|------------------|
| PARAMETER   |           | SYMBOL                            | TEST CONDITIONS                      | VALUES     | UNITS            |
| Maximum junction and storage temperature range          | ge        | T <sub>J</sub> , T <sub>Stg</sub> |                                      | -55 to 150 | °C               |
| Maximum thermal resistance junction to case per leg     | ,         | D                                 | DC operation                         | 2.0        |                  |
| Maximum thermal resistance junction to case per package |           | $R_{thJC}$                        | DC Operation                         | 1.0        | °C/W             |
| Typical thermal resistance, case to heatsink            |           | R <sub>thCS</sub>                 | Mounting surface, smooth and greased | 0.50       |                  |
| Approximate weight                                      |           |                                   |                                      | 2          | g                |
| Approximate weight                                      |           |                                   |                                      | 0.07       | oz.              |
| Mounting torque   | minimum   |                                   |                                      | 6 (5)      | kgf · cm         |
| Mounting torque -                                       | maximum   |                                   |                                      | 12 (10)    | (lbf $\cdot$ in) |
| Madina dade   |           |                                   | Case style D <sup>2</sup> PAK        | 42CTQ      | 030SH            |
| Marking device  |           |                                   | Case style TO-262                    | 42CTQ      | 030-1H           |



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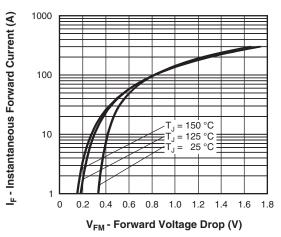


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

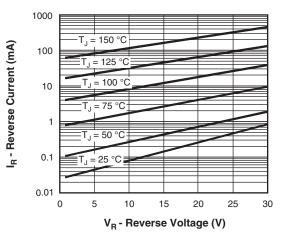


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

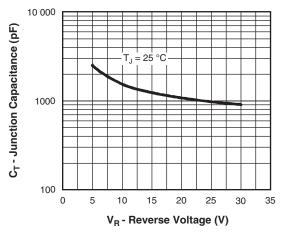


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

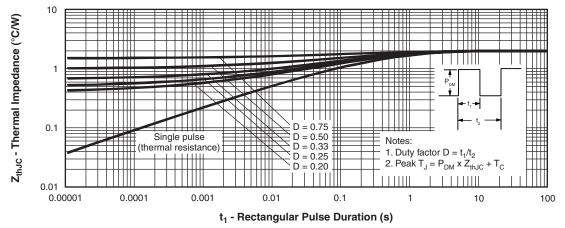


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



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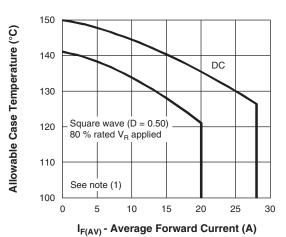
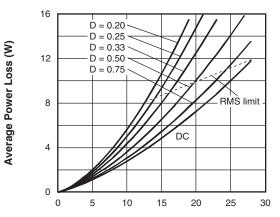


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)



I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)

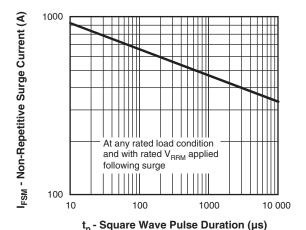


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

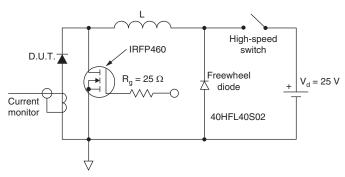


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

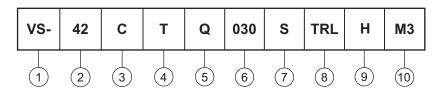
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 10 \text{ V}. \end{array}$ 

# VS-42CTQ030SHM3, VS-42CTQ030-1HM3

Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

#### Device code



1 - Vishay Semiconductors product

2 - Current rating (40 A)

- Circuit configuration: C = Common cathode

**4** - T = TO-220

5 - Schottky "Q" series

Voltage rating (030 = 30 V)

7 - • S = D<sup>2</sup>PAK

• -1 = TO-262

8 - • None = Tube

• TRL = Tape and reel (left oriented - for D<sup>2</sup>PAK only)

• TRR = Tape and reel (right oriented - for D<sup>2</sup>PAK only)

9 - H = AEC-Q101 qualified

- M3 = Halogen-free, RoHS-compliant and termination lead (Pb)-free

| ORDERING INFORMATION |                  |                        |                          |  |  |  |
|----------------------|------------------|------------------------|--------------------------|--|--|--|
| PREFERRED P/N        | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION    |  |  |  |
| VS-42CTQ030SHM3      | 50               | 1000                   | Antistatic plastic tubes |  |  |  |
| VS-42CTQ030STRRHM3   | 800              | 800                    | 13" diameter reel        |  |  |  |
| VS-42CTQ030STRLHM3   | 800              | 800                    | 13" diameter reel        |  |  |  |
| VS-42CTQ030-1HM3     | 50               | 1000                   | Antistatic plastic tubes |  |  |  |

| LINKS TO RELATED DOCUMENTS |                               |                          |  |  |
|----------------------------|-------------------------------|--------------------------|--|--|
| Dimensions —               | TO-263AB (D <sup>2</sup> PAK) | www.vishay.com/doc?95046 |  |  |
| Diffierisions —            | TO-262AA                      | www.vishay.com/doc?95419 |  |  |
| Part marking information — | TO-263AB (D <sup>2</sup> PAK) | www.vishay.com/doc?95444 |  |  |
| Fart marking information — | TO-262AA                      | www.vishay.com/doc?95443 |  |  |
| Packaging information      |                               | www.vishay.com/doc?95032 |  |  |



## Vishay Semiconductors

## D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



| SYMBOL   | MILLIMETERS |       | INC   | HES   | NOTES | SYMBOL  | MILLIM | ETERS | INC   | HES   | NOTES |
|----------|-------------|-------|-------|-------|-------|---------|--------|-------|-------|-------|-------|
| STIVIBUL | MIN.        | MAX.  | MIN.  | MAX.  | NOIES | STWIDOL | MIN.   | MAX.  | MIN.  | MAX.  | NOTES |
| Α        | 4.06        | 4.83  | 0.160 | 0.190 |       | D1      | 6.86   | 8.00  | 0.270 | 0.315 | 3     |
| A1       | 0.00        | 0.254 | 0.000 | 0.010 |       | Е       | 9.65   | 10.67 | 0.380 | 0.420 | 2, 3  |
| b        | 0.51        | 0.99  | 0.020 | 0.039 |       | E1      | 7.90   | 8.80  | 0.311 | 0.346 | 3     |
| b1       | 0.51        | 0.89  | 0.020 | 0.035 | 4     | е       | 2.54   | BSC   | 0.100 | ) BSC |       |
| b2       | 1.14        | 1.78  | 0.045 | 0.070 |       | Н       | 14.61  | 15.88 | 0.575 | 0.625 |       |
| b3       | 1.14        | 1.73  | 0.045 | 0.068 | 4     | L       | 1.78   | 2.79  | 0.070 | 0.110 |       |
| С        | 0.38        | 0.74  | 0.015 | 0.029 |       | L1      | -      | 1.65  | -     | 0.066 | 3     |
| c1       | 0.38        | 0.58  | 0.015 | 0.023 | 4     | L2      | 1.27   | 1.78  | 0.050 | 0.070 |       |
| c2       | 1.14        | 1.65  | 0.045 | 0.065 |       | L3      | 0.25   | BSC   | 0.010 | BSC   |       |
| D        | 8.51        | 9.65  | 0.335 | 0.380 | 2     | L4      | 4.78   | 5.28  | 0.188 | 0.208 |       |

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

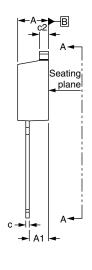


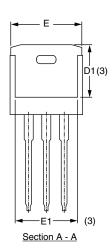
## Vishay Semiconductors

## **TO-262**

#### **DIMENSIONS** in millimeters and inches

# Modified JEDEC outline TO-262 (Datum A) (2) (3) (3) L1 D D D C C C C A (2) A (2) A (3) L2 B B B B C C C A (2)



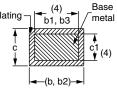


**⊕** 0.010**⋒**|A**⋒**|B

#### Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

| CYMPOL | MILLIN   | METERS | INCH  | IES   | NOTES |
|--------|----------|--------|-------|-------|-------|
| SYMBOL | MIN.     | MAX.   | MIN.  | MAX.  | NOTES |
| Α      | 4.06     | 4.83   | 0.160 | 0.190 |       |
| A1     | 2.03     | 3.02   | 0.080 | 0.119 |       |
| b      | 0.51     | 0.99   | 0.020 | 0.039 |       |
| b1     | 0.51     | 0.89   | 0.020 | 0.035 | 4     |
| b2     | 1.14     | 1.78   | 0.045 | 0.070 |       |
| b3     | 1.14     | 1.73   | 0.045 | 0.068 | 4     |
| С      | 0.38     | 0.74   | 0.015 | 0.029 |       |
| c1     | 0.38     | 0.58   | 0.015 | 0.023 | 4     |
| c2     | 1.14     | 1.65   | 0.045 | 0.065 |       |
| D      | 8.51     | 9.65   | 0.335 | 0.380 | 2     |
| D1     | 6.86     | 8.00   | 0.270 | 0.315 | 3     |
| E      | 9.65     | 10.67  | 0.380 | 0.420 | 2, 3  |
| E1     | 7.90     | 8.80   | 0.311 | 0.346 | 3     |
| е      | 2.54 BSC |        | 0.100 | BSC   |       |
| L      | 13.46    | 14.10  | 0.530 | 0.555 |       |
| L1     | -        | 1.65   | -     | 0.065 | 3     |
| L2     | 3.56     | 3.71   | 0.140 | 0.146 |       |

#### Notes

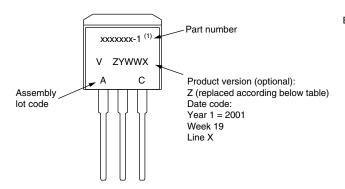
- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



# **Part Marking Information**

## Vishay Semiconductors

## **TO-262**



Example: This is a xxxxxxx-1 <sup>(1)</sup> with assembly lot code AC, assembled on WW 19, 2001

in the assembly line "X"

#### Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

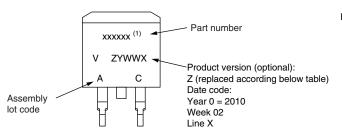
| ENVIRONMENTAL NAMING CODE (Z) | PRODUCT DEFINITION  |
|-------------------------------|---|
| A                             | Termination lead (Pb)-free                                  |
| В                             | Totally lead (Pb)-free                                      |
| E                             | RoHS-compliant and termination lead (Pb)-free               |
| F                             | RoHS-compliant and totally lead (Pb)-free                   |
| М                             | Halogen-free, RoHS-compliant and termination lead (Pb)-free |
| N                             | Halogen-free, RoHS-compliant and totally lead (Pb)-free     |
| G                             | Green   |



# **Part Marking Information**

Vishay Semiconductors

## D<sup>2</sup>PAK



Example: This is a xxxxxx <sup>(1)</sup> with assembly lot code AC, assembled on WW 02, 2010

#### Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

| ENVIRONMENTAL NAMING CODE (Z) | PRODUCT DEFINITION   |
|-------------------------------|--|
| А                             | Termination lead (Pb)-free                                   |
| В                             | Totally lead (Pb)-free                                       |
| E                             | RoHS-compliant and termination lead (Pb)-free                |
| F                             | RoHS-compliant and totally lead (Pb)-free                    |
| M                             | Halogen-free, RoHS-compliant, and termination lead (Pb)-free |
| N                             | Halogen-free, RoHS-compliant, and totally lead (Pb)-free     |
| G                             | Green  |



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